

Standard Rectifier

$$V_{RRM} = 2 \times 1600 \text{ V}$$

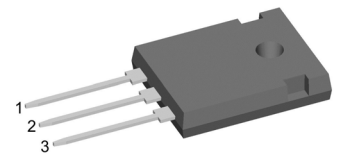
$$I_{FAV} = 30 \text{ A}$$

$$V_F = 1,23 \text{ V}$$


Phase leg

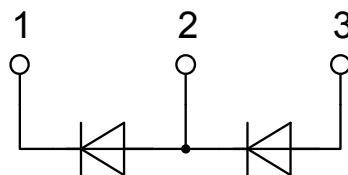
Part number

DMA30P1600HR



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

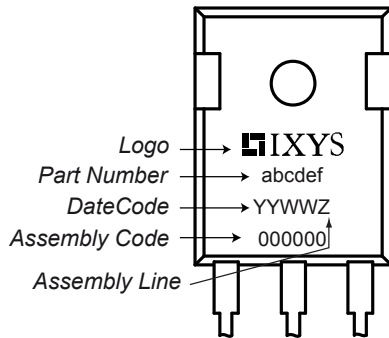
- Diode for main rectification
- For single and three phase bridge configurations

Package: ISO247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

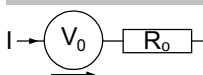
Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				1700	V	
V_{RRM}	max. repetitive reverse blocking voltage				1600	V	
I_R	reverse current	$V_R = 1600$ V			40	μ A	
		$V_R = 1600$ V			1,5	mA	
V_F	forward voltage drop	$I_F = 30$ A			1,28	V	
		$I_F = 60$ A			1,57	V	
		$I_F = 30$ A	$T_{VJ} = +02$ °C			1,23	V
		$I_F = 60$ A				1,63	V
I_{FAV}	average forward current	$T_C = 105$ °C 180° sine			30	A	
V_{FO}	threshold voltage	} for power loss calculation only			0,82	V	
r_F	slope resistance				13,5	m Ω	
R_{thJC}	thermal resistance junction to case				1,3	K/W	
R_{thCH}	thermal resistance case to heatsink			0,25		K/W	
P_{tot}	total power dissipation				115	W	
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45$ °C		300	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		325	A	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C		255	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		275	A	
I^2t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45$ °C		450	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		440	A ² s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C		325	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		315	A ² s	
C_J	junction capacitance	$V_R = 400$ V; f = 1 MH	$T_{VJ} = 25$ °C		10	pF	

Package ISO247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			50	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0,8		1,2	Nm
F_C	mounting force with clip		20		120	N
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	2,7			mm
$d_{Spb/Apb}$		terminal to backside	4,1			mm
V_{ISOL}	isolation voltage	t = 1 second	3600			V
		t = 1 minute	3000			V

Product Marking

Part description

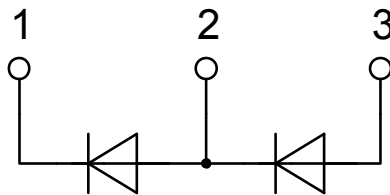
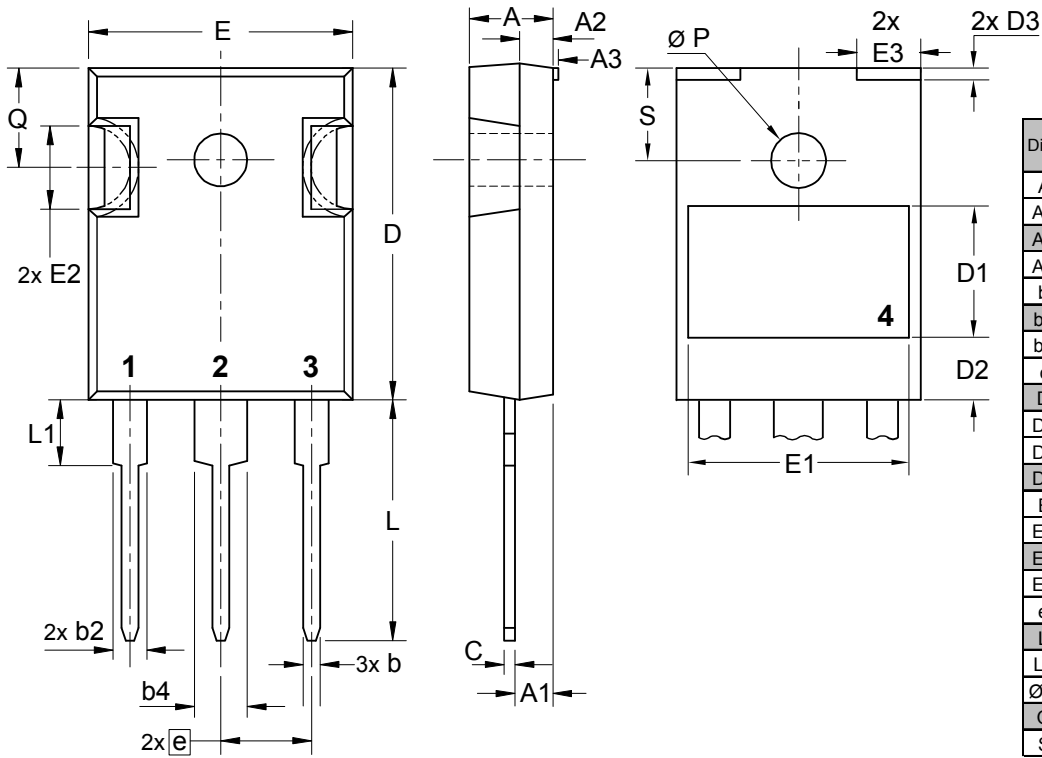
D = Diode
 M = Standard Rectifier
 A = (up to 1800V)
 30 = Current Rating [A]
 P = Phase leg
 1600 = Reverse Voltage [V]
 HR = ISO247 (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DMA30P1600HR	DMA30P1600HR	Tube	30	512442

Equivalent Circuits for Simulation
** on die level*
 $T_{VJ} = 175\text{ °C}$

Rectifier

$V_{0\ max}$	threshold voltage	0,82	V
$R_{0\ max}$	slope resistance *	10,9	mΩ

Outlines ISO247



Rectifier

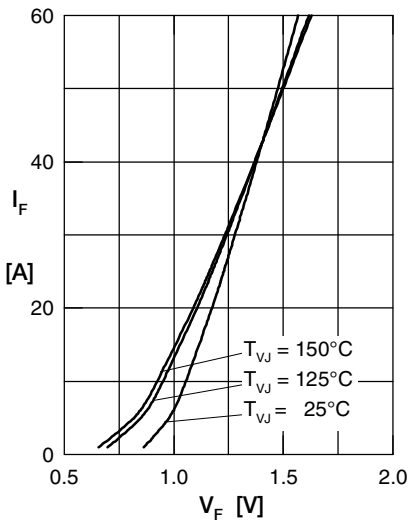


Fig. 1 Forward current versus voltage drop per diode

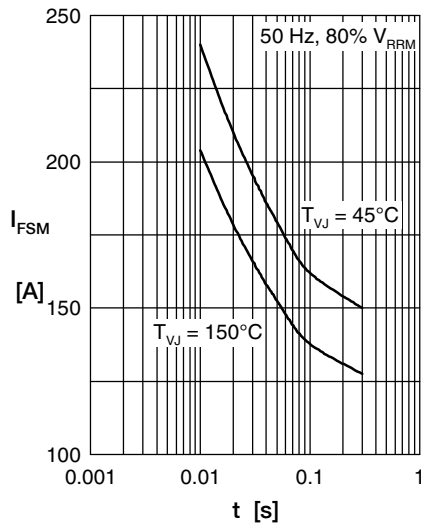


Fig. 2 Surge overload current vs. time per diode

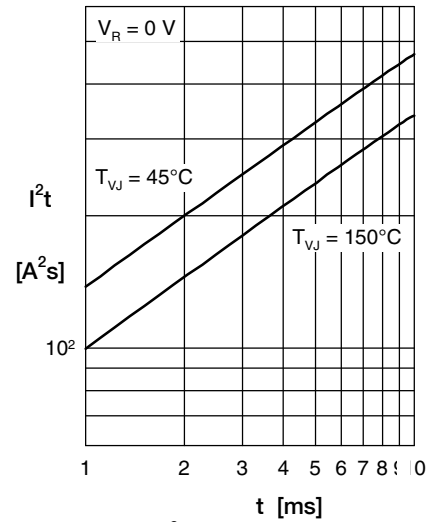


Fig. 3 I^2t versus time per diode

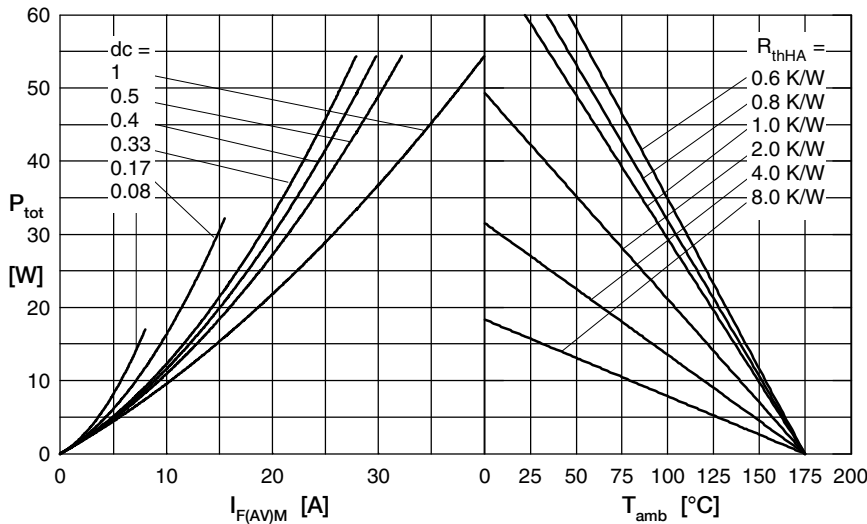


Fig. 4 Power dissipation vs. direct output current and ambient temperature per diode

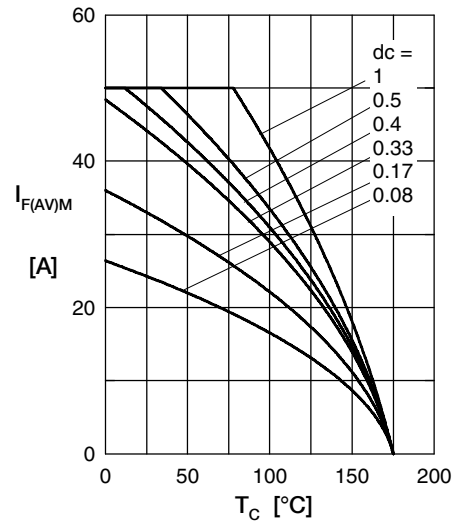


Fig. 5 Max. forward current vs. case temperature per diode

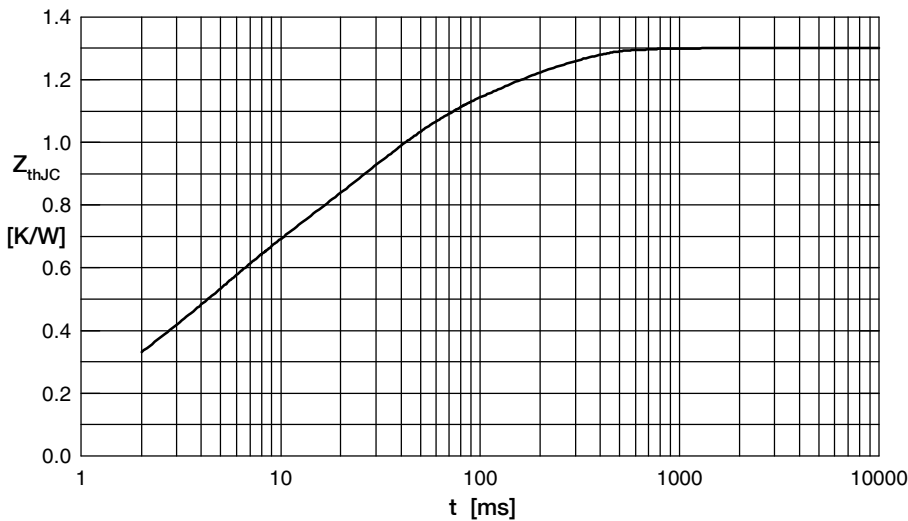


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.060	0.0004
2	0.170	0.0020
3	0.310	0.0040
4	0.470	0.0240
5	0.290	0.1500